Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 1.125 inches **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 900.0 breakover voltage, dc **Current Rating Per Characteristic:** 1000.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector blank Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a Unit Of Measure: Demilitarization: No Fiig: A110a0